AC Thyristor Triac power switch

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics		1			
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V_D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	20	mA
V _T	on-state voltage	I _T = 6 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.7	V
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	haracteristics	·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 4 A; dV _{com} /dt = 20 V/µs; (snubberless condition); gate open circuit; <u>Fig. 14</u> ; <u>Fig. 15</u>	4	-	-	A/ms
		V_D = 400 V; T _j = 125 °C; I _{T(RMS)} = 4 A; dV _{com} /dt = 10 V/µs; gate open circuit; Fig. 14; Fig. 15	5	-	-	A/ms
		$\label{eq:VD} \begin{array}{l} V_D = 400 \text{ V}; \text{T}_j = 125 \ ^\circ\text{C}; \text{I}_{\text{T}(\text{RMS})} = 4 \text{ A}; \\ \text{d} V_{\text{com}}/\text{d} \text{t} = 1 \ \text{V}/\mu\text{s}; \text{ gate open circuit}; \\ \hline \text{Fig. 14}; \ \hline \text{Fig. 15} \end{array}$	8	-	-	A/ms

5. Pinning information

Table 2.	Fable 2. Pinning information							
Pin	Symbol	Description	Simplified outline	Graphic symbol				
1	СМ	common		LD				
2	LD	load						
3	G	gate		G—				
mb	LD	mounting base; load	<u>لَّا حَدْ</u> المَا تَعْنَى اللَّهُ عَلَى المَاتِي المَاتِي المَاتِي المَاتِي المَاتِي المَاتِي المَاتِي المَاتِي المَاتِي الم	CM 003aaf296				

6. Ordering information

Table 3. Ordering information						
Type number	Package					
	Name	Description	Version			
ACTT4S-800E	DPAK	plastic single-ended surface-mounted package (DPAK); 3 leads (one lead cropped)	SOT428			

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7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	800	V
I _{T(RMS)}	RMS on-state current	full sine wave; T _{mb} ≤ 108 °C; <u>Fig. 1;</u> <u>Fig. 2; Fig. 3</u>	-	4	Α
I _{TSM}	non-repetitive peak on- state current	full sine wave; $T_{j(init)}$ = 25 °C; t_p = 20 ms; Fig. 4; Fig. 5	-	35	A
		full sine wave; T _{j(init)} = 25 °C; t _p = 16.7 ms	-	39	А
l ² t	I ² t for fusing	t _p = 10 ms; sine-wave pulse	-	6	A²s
dl _T /dt	rate of rise of on-state current	I _G = 20 mA	-	100	A/µs
I _{GM}	peak gate current	t = 20 µs	-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.5	W
Tj	junction temperature		-	125	°C
V _{PP}	peak pulse voltage	T _i = 25 °C; non-repetitive, off-state; <u>Fig. 6</u>	-	2	kV

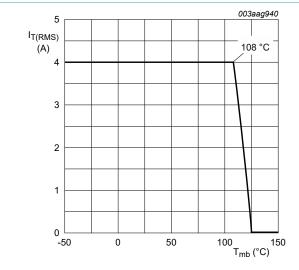
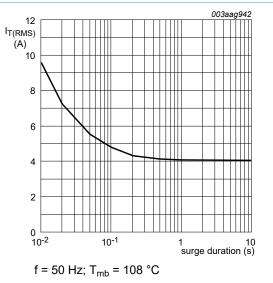
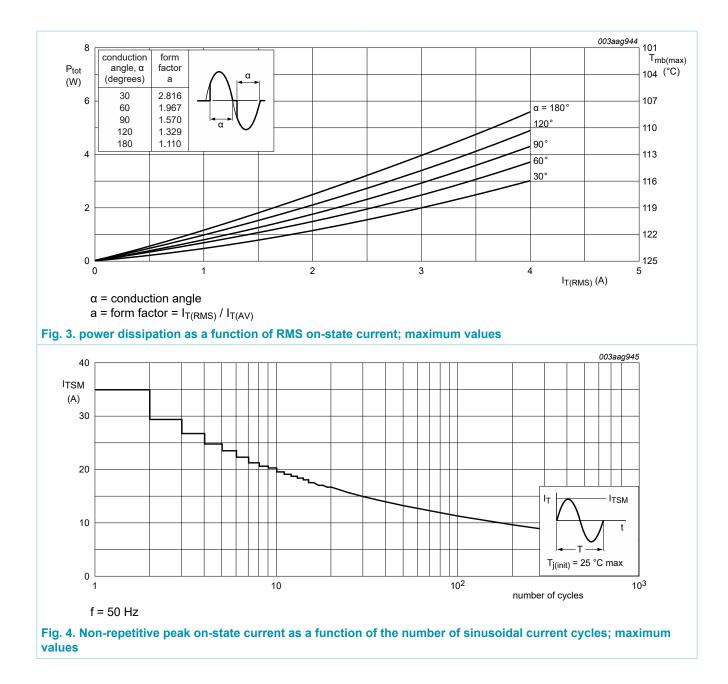


Fig. 1. RMS on-state current as a function of mounting base temperature; maximum values





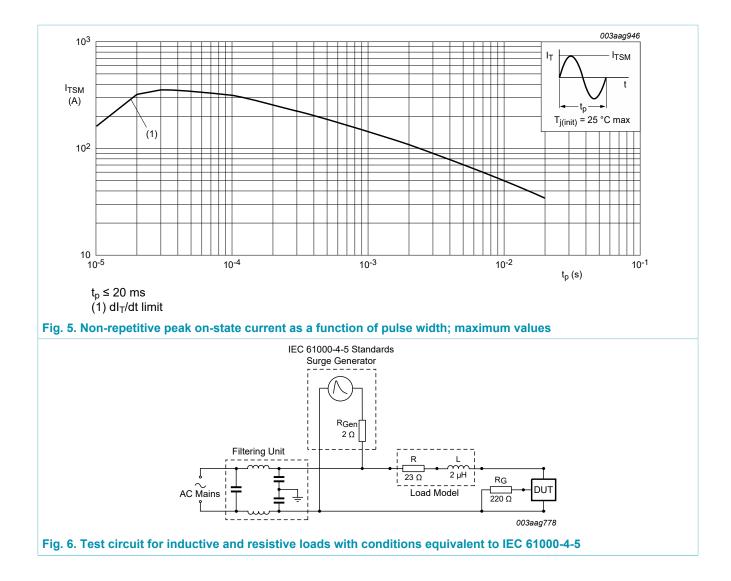
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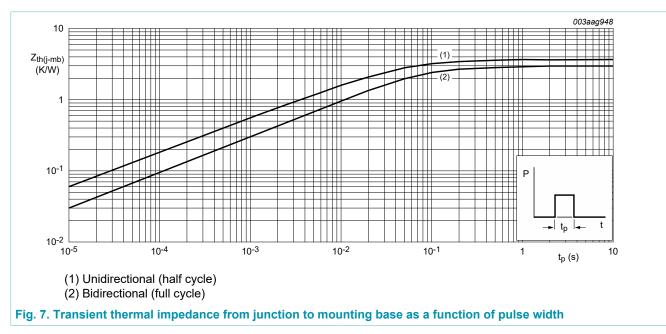
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8. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance from junction to mounting base	full cycle; <u>Fig. 7</u>	-	-	3	K/W
		half cycle; <u>Fig. 7</u>	-	-	3.7	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	75	-	K/W



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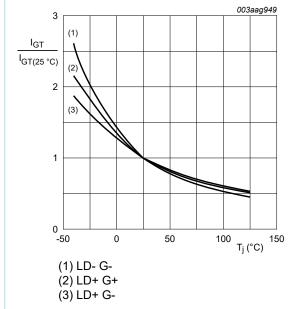
9. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	acteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
		V _D = 12 V; I _T = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 8</u>	-	-	10	mA
l	latching current	V _D = 12 V; I _G = 100 mA; LD+ G+; T _j = 25 °C; <u>Fig. 9</u>	-	-	30	mA
		V _D = 12 V; I _G = 100 mA; LD+ G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	40	mA
		V _D = 12 V; I _G = 100 mA; LD- G-; T _j = 25 °C; <u>Fig. 9</u>	-	-	30	mA
I _H	holding current	V _D = 12 V; T _j = 25 °C; <u>Fig. 10</u>	-	-	20	mA
V _T	on-state voltage	I _T = 6 A; T _j = 25 °C; <u>Fig. 11</u>	-	-	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 100 mA; T _j = 25 °C; <u>Fig. 12</u>	-	0.8	1	V
		V _D = 400 V; I _T = 100 mA; T _j = 125 °C; Fig. 12	0.2	0.45	-	V
I _D	off-state current	V _D = 800 V; T _j = 25 °C	-	-	10	μA
		V _D = 800 V; T _j = 125 °C	-	-	0.5	mA
V _{CL}	clamping voltage	I _{CL} = 0.1 mA; t _p = 1 ms; T _j = 25 °C	850	-	-	V
Dynamic ch	naracteristics	· · · · · ·				
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 536 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 13	500	-	-	V/µs
dl _{com} /dt	rate of change of commutating current	$V_D = 400 \text{ V}; \text{ T}_j = 125 \text{ °C}; \text{ I}_{T(RMS)} = 4 \text{ A};$ $dV_{com}/dt = 20 \text{ V/}\mu\text{s}; \text{ (snubberless condition); gate open circuit; Fig. 14;}$ Fig. 15	4	-	-	A/ms
		$V_D = 400 \text{ V}; \text{T}_\text{j} = 125 ^\circ\text{C}; \text{I}_\text{T(RMS)} = 4 \text{ A}; \\ \text{d}\text{V}_\text{com}/\text{d}\text{t} = 10 \text{ V}/\mu\text{s}; \text{ gate open circuit}; \\ \text{Fig. 14; Fig. 15}$	5	-	-	A/ms
		V_D = 400 V; T_j = 125 °C; $I_{T(RMS)}$ = 4 A; dV _{com} /dt = 1 V/µs; gate open circuit; Fig. 14; Fig. 15	8	-	-	A/ms

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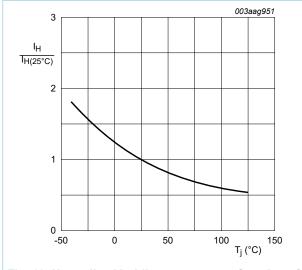
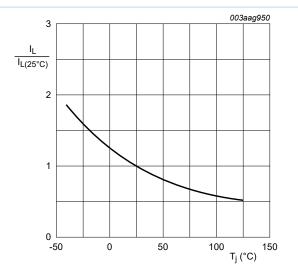
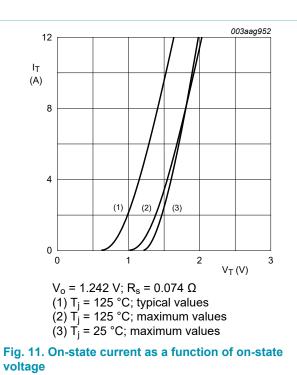


Fig. 10. Normalized holding current as a function of junction temperature





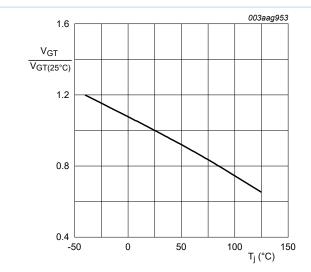


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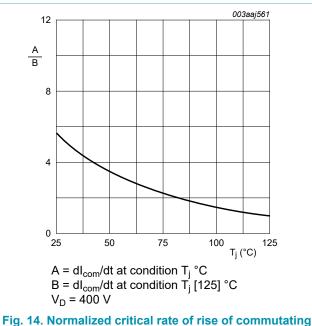
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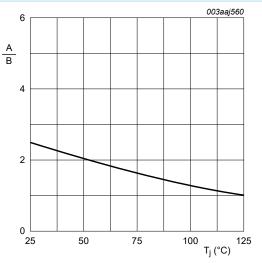
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A = dV_D/dt at condition T_j °C B = dV_D/dt at condition T_i [125] °C



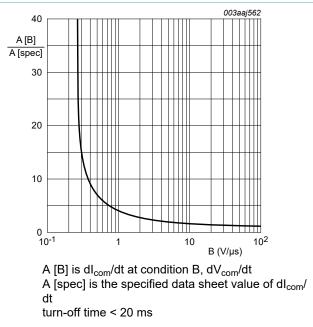


Fig. 15. Normalized critical rate of change of commutating current as a function of critical rate of change of commutating voltage; minimum values

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10. Package outline

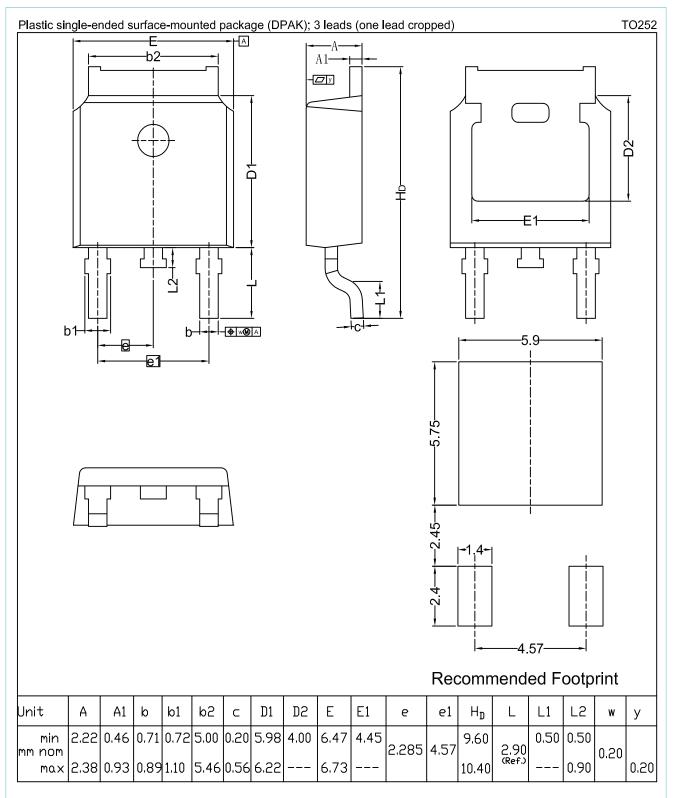


Fig. 16. Package outline DPAK (SOT428)

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